ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND0.3V to +4.1V	
\overline{EN} , CLKSEL, CLK_, \overline{CLK} , to GND0.3V to (V _{CC} + 0.3V)	
CLK to CLK±3V	Jun
Continuous Output Current	
Surge Output Current	
V _{BB} Sink/Source Current±0.65mA	Jun
Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
Single-Layer PC Board	Op
20-Pin TSSOP (derate 7.69mW/°C above +70°C)615mW	Jun
Multilayer PC Board	Sto
20-Pin TSSOP (derate 11mW/°C above +70°C)879mW	ESE
Junction-to-Ambient Thermal Resistance in Still Air	
Single-Laver PC Board	Lea
20-Pin TSSOP+130°C/W	200

Multilayer PC Board	
20-Pin TSSOP+91°C/W	
Junction-to-Ambient Thermal Resistance with 500LFPM	
Airflow Single-Layer PC board	
20-Pin TSSOP+96°C/W	
Junction-to-Case Thermal Resistance	
20-Pin TSSOP+20°C/W	
Operating Temperature Range40°C to +85°C	
Junction Temperature+150°C	
Storage Temperature Range65°C to +150°C	
ESD Protection	
Human Body Model (inputs and outputs)	
Lead Temperature (soldering, 10s)+300°C	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{CC} - GND = 3V \text{ to } 3.6V, \text{ outputs terminated with } 100\Omega \pm 1\%, \text{ unless otherwise noted. Typical values are at V_{CC} - GND = 3.3V, V_{IHD} = V_{CC} - 1.0V, V_{ILD} = V_{CC} - 1.5V, \text{ unless otherwise noted.})$ (Notes 1, 2, and 3)

DADAMETED		CONDITIONS	-40°C			+25°C			+85°C			
PARAMETER	SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	MIN	ТҮР	MAX	UNITS
SINGLE-ENDED	INPUTS (CI	LKSEL, EN)										
Input High Voltage	VIH		V _{CC} - 1.165		V _{CC} - 0.88	V _{CC} - 1.165		V _{CC} - 0.88	V _{CC} - 1.165		V _{CC} - 0.88	V
Input Low Voltage	VIL		V _{CC} - 1.81		V _{CC} - 1.475	V _{CC} - 1.81		V _{CC} - 1.475	V _{CC} - 1.81		V _{CC} - 1.475	V
Input Current	l _{IN}	Vih(max), Vil(max)	-10		+70	-10		+70	-10		+70	μΑ
DIFFERENTIAL I	NPUTS (CL	K_, <u>CLK_</u>)										
Single-Ended Input High Voltage	VIH	Figure 1	V _{CC} - 1.125		V _{CC} - 0.88	V _{CC} - 1.165		V _{CC} - 0.88	V _{CC} - 1.165		V _{CC} - 0.88	V
Single-Ended Input Low Voltage	VIL	Figure 1	V _{CC} - 1.81		V _{CC} - 1.475	V _{CC} - 1.81		V _{CC} - 1.475	V _{CC} - 1.81		V _{CC} - 1.495	V
Differential Input High Voltage	VIHD	Figure 2	1.2		Vcc	1.2		Vcc	1.2		V _{CC}	V
Differential Input Low Voltage	VILD	Figure 2	GND		V _{CC} - 0.095	GND		V _{CC} - 0.095	GND		V _{CC} - 0.095	V
Differential Input Voltage	VID	VIHD - VILD	0.095		3.0	0.095		3.0	0.095		3.0	V
Input Current	I _{IH} , IIL	CLK_, or $\overline{\text{CLK}}$ = V _{IHD} or V _{ILD}	-100		+100	-100		+100	-100		+100	μΑ

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DC ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} - GND = 3V \text{ to } 3.6V, \text{ outputs terminated with } 100\Omega \pm 1\%, \text{ unless otherwise noted. Typical values are at } V_{CC} - GND = 3.3V, V_{IHD} = V_{CC} - 1.0V, V_{ILD} = V_{CC} - 1.5V, \text{ unless otherwise noted.}$ (Notes 1, 2, and 3)

PARAMETER	SYMBOL	CONDITIONS	-40°C				+25°C		+85°C			
	SYMBOL		MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
OUTPUTS (Q_, G	<u>,</u>)											
Output High Voltage	V _{OH}	Figure 2			1.6			1.6			1.6	V
Output Low Voltage	V _{OL}	Figure 2	0.9			0.9			0.9			V
Differential Output Voltage	V _{OD}	V _{OH} - V _{OL} , Figure 2	250	350	450	250	350	450	250	350	450	mV
Change in V _{OD} Between Complementary Output States	ΔV _{OD}				50			50			50	mV
Output Offset Voltage	V _{OS}		1.125	1.25	1.375	1.125	1.25	1.375	1.125	1.25	1.375	mV
Change in VOS Between Complementary Output States	ΔVOCM				25			25			25	mV
Outout Chart		$Q_{shorted}$ to $\overline{Q_{}}$			12			12			12	
Output Short- Circuit Current	losc	$Q_or \overline{Q_o}$ shorted to GND			29			29			29	mA
REFERENCE									•			
Reference Voltage Output	V_{BB}	I _{BB} = ±0.65mA (Note 4)	V _{CC} - 1.38		V _{CC} - 1.22	V _{CC} - 1.38		V _{CC} - 1.26	V _{CC} - 1.40		V _{CC} - 1.26	V
POWER SUPPLY	/		-									
Power-Supply Current	Icc	(Note 5)		45	75		48	75		51	75	mA

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AC ELECTRICAL CHARACTERISTICS

 $(V_{CC} - GND = 3V \text{ to } 3.6V, \text{ outputs terminated with } 100\Omega \pm 1\%, f_{IN} \le 1.0GHz, \text{ input transition time} = 125ps (20\% \text{ to } 80\%), V_{IHD} - V_{ILD} = 0.15V \text{ to } V_{CC}, \text{ unless otherwise noted}. Typical values are at V_{CC} - GND = 3.3V, V_{IHD} = V_{CC} - 1.0V, V_{ILD} = V_{CC} - 1.5V, unless otherwise noted.) (Notes 1 and 6)$

DADAMETER	0/4/5/01		-40°C			+25°C			+85°C			
PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
Propagation Delay CLK_, CLK_ to Q_, Q_	tphl, tplh	Figure 2	250	340	600	250	340	600	250	340	600	ps
Output-to- Output Skew	tskoo	(Note 7)		10	30		8	25		20	45	ps
Part-to-Part Skew	^t SKPP	(Note 8)			145			145			145	ps
Added Random Jitter	t _{RJ}	f _{IN} = 1.0GHz, clock pattern (Note 9)		0.3	1.0		0.3	1.0		0.3	1.0	ps (RMS)
Added Deterministic Jitter	tDJ	$f_{IN} = 1.0Gsps,$ $2^{23} - 1 PRBS$ pattern (Note 9)		50	60		50	60		50	60	ps (P-P)
Operating Frequency	fMAX	$V_{OD} \ge 250 mV$	1.0			1.0			1.0			GHz
Differential Output Rise/Fall Time	t _{R/tF}	20% to 80%, Figure 2	140	205	300	140	205	300	140	205	300	ps

Note 1: Measurements are made with the device in thermal equilibrium.

Note 2: Current into a pin is defined as positive. Current out of a pin is defined as negative.

Note 3: DC parameters are production tested at +25°C. DC limits are guaranteed by design and characterized over the full operating temperature range.

Note 4: Use V_{BB} only for inputs that are on the same device as the V_{BB} reference.

Note 5: All pins are open except V_{CC} and GND, all outputs are loaded with 100Ω differentially.

Note 6: Guaranteed by design and characterization. Limits are set to ±6 sigma.

Note 7: Measured between outputs of the same part at the signal crossing points for a same-edge transition.

Note 8: Measured between outputs of different parts at the signal crossing points under identical conditions for a same-edge transition.

Note 9: Device jitter added to the input signal.

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Typical Operating Characteristics

 $(V_{CC} - GND = 3.3V)$, outputs terminated with $100\Omega \pm 1\%$, $f_{IN} = 1.0GHz$, input transition time = 125ps (20% to 80%), $V_{IHD} = V_{CC} - 1.0V$, $V_{ILD} = V_{CC} - 1.5V$, unless otherwise noted.)











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Pin Description

PIN	NAME	FUNCTION
1	Q0	Noninverting Differential Output 0. Typically terminated with 100Ω to $\overline{Q0}$.
2	QO	Inverting Differential Output 0. Typically terminated with 100Ω to Q0.
3	Q1	Noninverting Differential Output 1. Typically terminated with 100Ω to $\overline{Q1}$.
4	Q1	Inverting Differential Output 1. Typically terminated with 100Ω to Q1.
5	Q2	Noninverting Differential Output 2. Typically terminated with 100 Ω to $\overline{\Omega^2}$.
6	Q2	Inverting Differential Output 2. Typically terminated with 100 Ω to Q2.
7	Q3	Noninverting Differential Output 3. Typically terminated with 100 Ω to $\overline{Q3}$.
8	$\overline{Q3}$	Inverting Differential Output 3. Typically terminated with 100 Ω to Q3.
9	Q4	Noninverting Differential Output 4. Typically terminated with 100Ω to $\overline{Q4}$.
10	$\overline{Q4}$	Inverting Differential Output 4. Typically terminated with 100 Ω to Q4.
11	GND	Ground
12	CLKSEL	Clock Select Input. Drive low to select the CLK0, $\overline{\text{CLK0}}$ input. Drive high to select the CLK1, $\overline{\text{CLK1}}$ input. The CLKSEL threshold is equal to V _{BB} . Internal 60k Ω pulldown to GND.
13	CLK0	Noninverting Differential Clock Input 0. Internal 75k Ω pulldown to GND.
14	CLKO	Inverting Differential Clock Input 0. Internal 75k Ω pullup to V _{CC} and 75k Ω pulldown to GND.
15	V _{BB}	Reference Output Voltage. Connect to the inverting or noninverting clock input to provide a reference for single-ended operation. When used, bypass with a 0.01μ F ceramic capacitor to V _{CC} ; otherwise, leave open.
16	CLK1	Noninverting Differential Input 1. Internal 75k Ω pulldown to GND.
17	CLK1	Inverting Differential Input 1. Internal 75k Ω pullup to V _{CC} and 75k Ω pulldown to GND.
18, 20	V _{CC}	Positive Supply Voltage. Bypass V_{CC} to GND with 0.1µF and 0.01µF ceramic capacitors. Place the capacitors as close to the device as possible with the smaller value capacitor closest to the device.
19	ĒN	Output Enable Input. Outputs are synchronously enabled on the falling edge of the selected clock input when $\overline{\text{EN}}$ is low. Outputs are synchronously driven to a differential low state on the falling edge of the selected clock input when $\overline{\text{EN}}$ is high. Internal 60k Ω pulldown to GND (Figure 3).

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Figure 1. MAX9310A Switching Characteristics with Single-Ended Input



Figure 2. MAX9310A Timing Diagram

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Figure 3. MAX9310A Timing EN Diagram

Detailed Description

The MAX9310A is a low-skew 1:5 differential driver with two selectable LVPECL inputs and LVDS outputs, designed for clock distribution applications. The selected clock accepts a differential input signal and reproduces it on five separate differential LVDS outputs. The inputs are biased with internal resistors such that the output is differential low when inputs are open. An onchip V_{BB} reference output is available for single-ended input operation. The device is guaranteed to operate at frequencies up to 1.0GHz with LVDS output levels conforming to the EIA/TIA-644 standard.

The MAX9310A is designed for 3V to 3.6V operation in systems with a nominal 3.3V supply.

Differential LVPECL Input

The MAX9310A has two input differential pairs that accept differential LVPECL/HSTL inputs, and can be configured to accept single-ended LVPECL inputs through the use of the V_{BB} voltage-reference output. Each differential input pair has to be independently terminated. A select pin (CLKSEL) is used to activate the desired input. The maximum magnitude of the differential signal applied to the input is 3V. Specifications for the high and low voltages of a differential input (V_{IHD} and V_{ILD}) and the differential input voltage (V_{IHD} - V_{ILD}) apply simultaneously.

Single-Ended Inputs and VBB

The differential inputs can be configured to accept a single-ended input through the use of the V_{BB} reference voltage. A noninverting, single-ended input is produced by connecting V_{BB} to the $\overline{\text{CLK}}$ input and applying a single-ended signal to the $\overline{\text{CLK}}$ input. Similarly, an inverting input is produced by connecting V_{BB} to the CLK_ input and applying the signal to the $\overline{\text{CLK}}$ input. With a differential input configured as single ended (using V_{BB}), the single-ended input can be driven to V_{CC} and GND, or with a single-ended LVPECL signal. Note the single-ended input must be at least V_{BB} ±95mV or a differential input of at least 95mV

to switch the outputs to the V_OH and V_OL levels specified in the DC Electrical Characteristics table (Figure 1).

When using the V_{BB} reference output, bypass it with a 0.01µF ceramic capacitor to V_{CC}. If the V_{BB} reference is not used, leave unconnected. The V_{BB} reference can source or sink 500µA. Use V_{BB} only for inputs that are on the same device as the V_{BB} reference.

Synchronous Enable

The MAX9310A is synchronously enabled and disabled with outputs in a differential low state to eliminate shortened clock pulses. \overline{EN} is connected to the input of an edge-triggered D flip-flop. After power-up, drive \overline{EN} low and toggle the selected clock input to enable the outputs. The outputs are enabled on the falling edge of the selected clock input after \overline{EN} goes low. The outputs are set to a differential low state on the falling edge of the selected clock input after \overline{EN} goes high (Figure 3).

Input Bias Resistors

Internal biasing resistors ensure a (differential) output low condition in the event that the inputs are not connected. The inverting input (\overline{CLK}_{-}) is biased with a 75k Ω pulldown to GND and a 75k Ω pullup to V_{CC}. The noninverting input (CLK_) is biased with a 75k Ω pulldown to GND.

Differential LVDS Output

The LVDS outputs must be terminated with 100Ω across Q and \overline{Q} , as shown in the *Typical Application Circuit*. The outputs are short-circuit protected.



Applications Information

Supply Bypassing

Bypass each V_{CC} to GND with high-frequency surfacemount ceramic 0.1 μ F and 0.01 μ F capacitors in parallel as close to the device as possible, with the 0.01 μ F capacitor closest to the device. Use multiple parallel vias to minimize parasitic inductance. When using the V_{BB} reference output, bypass it with a 0.01 μ F ceramic capacitor to V_{CC}. If the V_{BB} reference is not used, it can be left open.

Controlled-Impedance Traces

Input and output trace characteristics affect the performance of the MAX9310A. Connect high-frequency input and output signals to 50Ω characteristic impedance traces. Minimize the number of vias to prevent impedance discontinuities. Reduce reflections by maintaining the 50 Ω characteristic impedance through cables and connectors. Reduce skew within a differential pair by matching the electrical length of the traces.

Output Termination

Terminate the outputs with 100Ω across Q_ and \overline{Q}_{-} , as shown in the *Typical Application Circuit*.

_Chip Information

TRANSISTOR COUNT: 716 PROCESS: Bipolar

Functional Diagram



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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